

TOSHIBA CMOS Linear Integrated Circuit Silicon Monolithic

TC75S103F

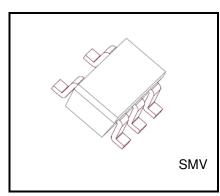
Single Operational Amplifier Low supply current

Features

- Input, Output Full Range type (Rail to Rail)
- Low supply current 100μA (Typ.) @V_{DD}=1.8V
- Low Input offset voltage 1.5mV (Max) @V_{DD}=1.8V
- Wide Operating Voltage Range 1.8V to 5.5V

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	
Supply voltage	V _{DD} - V _{SS}	6	٧
Differential input voltage	DVIN	±6	V
Input voltage	V _{IN}	V _{DD} to V _{SS}	٧
Output voltage	V _{OUT}	V_{SS} -0.3V to V_{DD} +0.3V \leq V_{SS} + 6V	٧
Output current	lout	±25	mA
Power dissipation	PD	200	mW
Operating temperature	T _{opr}	-40 to 105	°C
Storage temperature	T _{stg}	-55 to 150	°C



Weight: SMV (SOT-25)(SC-74A) :14 mg (typ.)

Note1: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ratings ($Ta = -40 \text{ to } 105^{\circ}\text{C}$)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{DD} - V _{SS}	1.8 to 5.5	V

Note2: A higher load capacitance will increase the risk of voltage oscillation. Allow sufficient capacitance value when designing your circuit and using this product to prevent voltage oscillation.

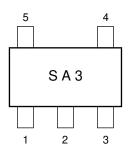
Note3: This device is sensitive to electrostatic discharge.

Please ensure equipment, operator and tools are adequately earthed when handling.

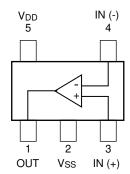
Start of commercial production 2020-09



Marking (top view)



Pin Assignment (top view)



Electrical Characteristics

DC Characteristics (V_{DD} = 1.8V, V_{SS} = GND, Ta = 25°C, V_{IN} = V_{DD}/2, unless otherwise noted.)

<u> </u>	<u> </u>		<u> </u>				
Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input offset voltage	V _{IO}	1	Rs = 1 kΩ, R _F = 100kΩ Ta = -40 to 105°C	-1.85	0.3	1.85	mV
	VIO	'	R _S = 1 kΩ, R _F = 100kΩ Ta = 25°C	-1.5	0.3	1.5	mV
Input offset voltage drift	V _{IO} drift	1	$R_S = 1 \text{ k}\Omega, R_F = 100\text{k}\Omega$	-	1	-	μV/°C
Input offset current	I _{IO}	2	-	-	1	-	рА
Input bias current	lį	2	-	-	1	-	рА
Common mode input voltage	CMVIN	3	$R_S = 1 \text{ k}\Omega, R_F = 100\text{k}\Omega$	0	-	V _{DD}	V
Voltage gain (open loop)	Gv	-	-	85	100	-	dB
Maximum autout valtage	VoH	4	$R_L \ge 100 \text{ k}\Omega$	1.7	-	-	V
Maximum output voltage	V _{OL}	5	$R_L \ge 100 \ k\Omega$	-	-	0.1	V
Common mode input signal rejection ratio	CMRR	3	V _{IN} = 0 to 1.8V	60	80	-	dB
Supply voltage rejection ratio	SVRR	1	V _{DD} = 1.8 to 5.0V	70	85	-	dB
Supply current	I _{DD}	6	-	-	100	165	μА
Source current	I _{source}	7	-	1.2	2	-	mA
Sink current	I _{sink}	8	-	1	2	-	mA

AC Characteristics (VDD = 0.9 V, Vss = -0.9 V, Ta = 25°C)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Unity Gain Cross Frequency	f⊤	-	-	-	0.3	-	MHz
Phase margin	Фт	-	-	-	40	-	degrees
Slew Rate	SR	-	-	-	0.52	-	V/μs



DC Characteristics (V_{DD} = 3.3V, V_{SS} = GND, Ta = 25°C, V_{IN} = V_{DD}/2, unless otherwise noted.)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input offset voltage	Vio	1	$R_S = 1 \text{ k}\Omega, R_F = 100 \text{k}\Omega$ $Ta = -40 \text{ to } 105^{\circ}\text{C}$	-2.15	0.4	2.15	mV
	VIO	'	Rs = 1 kΩ, R _F = 100kΩ Ta = 25°C	-1.85	0.4	1.85	mV
Input offset voltage drift	V _{IO} drift	1	Rs = 1 k Ω , RF = 100k Ω	-	2	-	μV/°C
Input offset current	lio	2	-	-	1	-	pА
Input bias current	lı .	2	-	-	1	-	pА
Common mode input voltage	CMVIN	3	Rs = 1 k Ω , RF = 100k Ω	0	-	V _{DD}	V
Voltage gain (open loop)	Gv	-	-	100	125	-	dB
Maximum autaut valtaga	Voн	4	$R_L \ge 100 \text{ k}\Omega$	3.2	-	-	V
Maximum output voltage	V _{OL}	5	$R_L \ge 100 \ k\Omega$	-	-	0.1	V
Common mode input signal rejection ratio	CMRR	3	V _{IN} = 0 to 3.3V	65	90	-	dB
Supply current	I _{DD}	6	-	-	100	165	μА
Source current	I _{source}	7	-	6	10	-	mA
Sink current	I _{sink}	8	-	6	10	-	mA

AC Characteristics (V_{DD} = 1.65 V, V_{SS} = -1.65 V, Ta = 25°C)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Unity Gain Cross Frequency	f⊤	-	-	-	0.36	-	MHz
Phase margin	Фт	-	-	1	60	-	degrees
Slew Rate	SR	-	-	-	0.4	-	V/µs



DC Characteristics (V_{DD} = 5.0V, V_{SS} = GND, Ta = 25°C, V_{IN} = V_{DD}/2, unless otherwise noted.)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input offset voltage	Vio	1	$R_S = 1 \text{ k}\Omega, R_F = 100\text{k}\Omega$ $Ta = -40 \text{ to } 105^{\circ}\text{C}$	-2.15	0.4	2.15	mV
	Vio		R _S = 1 kΩ, R _F = 100kΩ Ta = 25°C	-1.85	0.4	1.85	mV
Input offset voltage drift	Viodrift	1	$R_S = 1 \text{ k}\Omega, R_F = 100\text{k}\Omega$	-	2	-	μV/°C
Input offset current	lio	2	-	-	1	-	pА
Input bias current	l _l	2	-	-	1	-	pА
Common mode input voltage	CMVIN	3	$R_S = 1 \text{ k}\Omega, R_F = 100\text{k}\Omega$	0	-	V _{DD}	V
Voltage gain (open loop)	Gv	-	-	100	125	-	dB
Maximum autaut valtaga	Voн	4	$R_L \ge 100 \text{ k}\Omega$	4.9	-	-	V
Maximum output voltage	V _{OL}	5	$R_L \ge 100 \text{ k}\Omega$	-	-	0.1	V
Common mode input signal rejection ratio	CMRR	3	V _{IN} = 0 to 5.0V	68	90	-	dB
Supply current	I _{DD}	6	-	-	115	190	μА
Source current	I _{source}	7	-	17	-	-	mA
Sink current	I _{sink}	8	-	17	-	-	mA

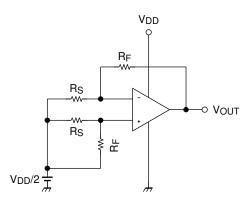
AC Characteristics (V_{DD} = 2.5 V, V_{SS} = -2.5 V, Ta = 25°C)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Unity Gain Cross Frequency	fŢ	-	-	1	0.37	-	MHz
Phase margin	Фт	-	-	-	60	-	degrees
Slew Rate	SR	-	-	-	0.4	-	V/μs



Test Circuit

1. SVRR, Vio



- **SVRR**
- For each of the two VDD values, measure the VOUT value, as indicated below, and calculate the value of SVRR using the equation shown.

When
$$V_{DD} = 1.8 \text{ V}$$
, $V_{DD} = V_{DD1}$ and $V_{OUT} = V_{OUT1}$
When $V_{DD} = 5.0 \text{ V}$, $V_{DD} = V_{DD2}$ and $V_{OUT} = V_{OUT2}$

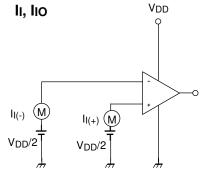
$$\text{SVRR=20log} \left[\left| \frac{V_{\text{DD1}} \text{-} V_{\text{DD2}}}{\left\{ V_{\text{OUT1}} \text{-} \left(\frac{V_{\text{DD1}}}{2} \right) \right\} \text{-} \left\{ V_{\text{OUT2}} \text{-} \left(\frac{V_{\text{DD2}}}{2} \right) \right\}} \right| \times \frac{R_{\text{F}} \text{+} R_{\text{S}}}{R_{\text{S}}} \right]$$

 V_{IO}

Measure the value of Vout and calculate the value of Vio using the following

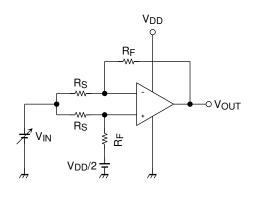
$$V_{IO} = \left(V_{OUT} - \frac{V_{DD}}{2}\right) \times \frac{R_S}{R_F + R_S}$$





- $I_{I} = (|I_{I(-)}| + |I_{I(+)}|) / 2$
- $I_{IO} = |I_{I(-)}| |I_{I(+)}|$

CMRR, CMVIN



CMRR

Measure the VouT value, as indicated below, and calculate the value of the CMRR using the equation shown.

When $V_{IN} = 0 V$, $V_{IN} = V_{IN1}$ and $V_{OUT} = V_{OUT1}$

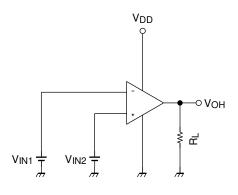
When V_{IN} = 3.3 V, V_{IN} = V_{IN2} and V_{OUT} = V_{OUT2}

$$\text{CMRR=20log}\left(\left|\frac{V_{\text{IN1}} - V_{\text{IN2}}}{V_{\text{OUT1}} - V_{\text{OUT2}}}\right| \times \frac{R_{\text{F}} + R_{\text{S}}}{R_{\text{S}}}\right)$$

CMVIN

Input range within which the CMRR specification guarantees V_{OUT} value (as varied by the V_{IN} value).

4. Voh

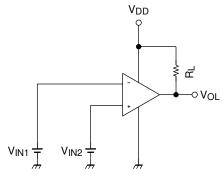


$$V_{IN1} = \frac{V_{DD}}{2} - 0.05V$$

$$V_{IN2} = \frac{V_{DD}}{2} + 0.05V$$



5. Vol

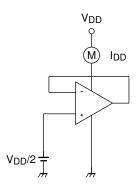


V_{OL}

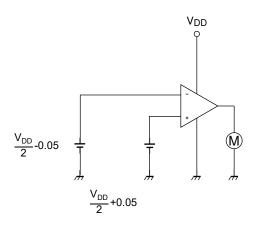
$$V_{IN1} = \frac{V_{DD}}{2} + 0.05V$$

$$V_{IN2} = \frac{V_{DD}}{2} - 0.05V$$

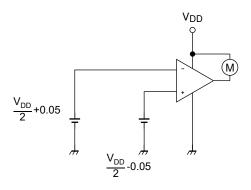
IDD 6.



7. I_{source}



8. Isink

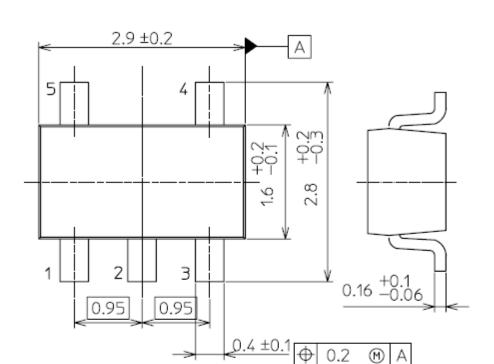


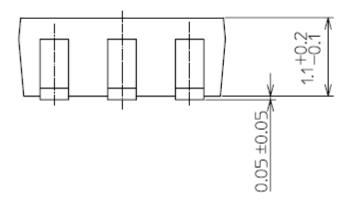
Unit: mm



Package Dimensions

SMV (SOT-25)(SC-74A)





Weight: 14 mg (typ.)



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